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ON Semiconductor®

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October 2016



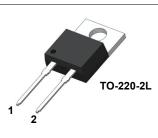
ON Semiconductor® FFSP20120A Silicon Carbide Schottky Diode 1200 V, 20 A

Features

- Max Junction Temperature 175 °C
- Avalanche Rated 200 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

Applications

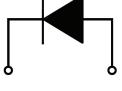
- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



1. Cathode 2. Anode

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.



1. Cathode 2

2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Unit
V _{RRM}	Peak Repetitive Reverse Voltage		1200	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)		200	mJ
l _F	Continuous Rectified Forward Current @ T _C < 148 °C		20	А
1	Non-Repetitive Peak Forward Surge Current	T _C = 25 °C, 10 μs	1190	А
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 150 ^o C, 10 μs	1200 200 20 1190 990 135 74 340 57 -55 to +175	А
I _{F,SM}	Non-RepetitiveForwardSurgeCurrent	Half-Sine Pulse, t _p = 8.3 ms	135	А
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	74	Α
Dtat	Dewer Dissignation	T _C = 25 °C	340	W
Ptot	Power Dissipation $T_{\rm C} = 150 ^{\circ}{\rm C}$		57	W
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
Thermal (Characteristics			
Symbol	Parameter		Ratings	Unit

Symbol	Parameter	Ratings	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.44	°C/W

FFSP20120A — Silicon Carbide Schottky Diode

Package	Marking	and	Orderina	Information
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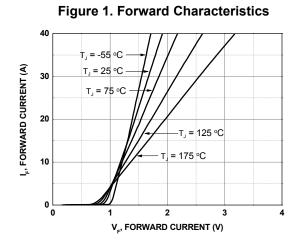
Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP20120A	FFSP20120A	TO-220-2L	Tube	N/A	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
		I _F = 20 A, T _C = 25 °C	-	1.45	1.75	
V _F	Forward Voltage	I _F = 20 A, T _C = 125 °C	-	1.7	2	V
		I _F = 20 A, T _C = 175 ^o C	-	2	2.4	
I _R	Reverse Current	VR = 1200 V, T _C = 25 °C	-	-	200	μΑ
		VR = 1200 V, T _C = 125 °C	-	-	300	
		VR = 1200 V, T _C = 175 °C	-	-	400	
Q _C	Total Capacitive Charge	V = 800 V	-	120	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	1220	-	pF
		V _R = 400 V, f = 100 kHz	-	111	-	
		V _R = 800 V, f = 100 kHz	-	88	-	

Notes: 1: EAS of 200 mJ is based on starting T_J = 25 °C, L = 0.5 mH, I_{AS} = 29 A, V = 150 V.

Typical Characteristics T_J = 25 °C unless otherwise noted.





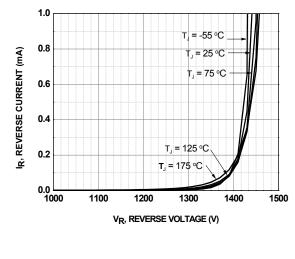
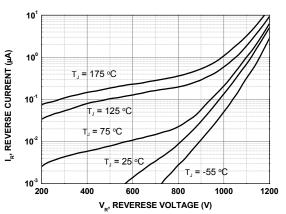
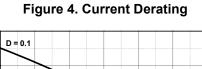
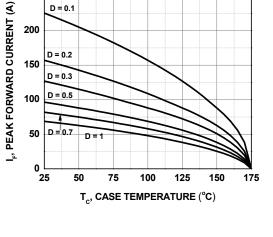


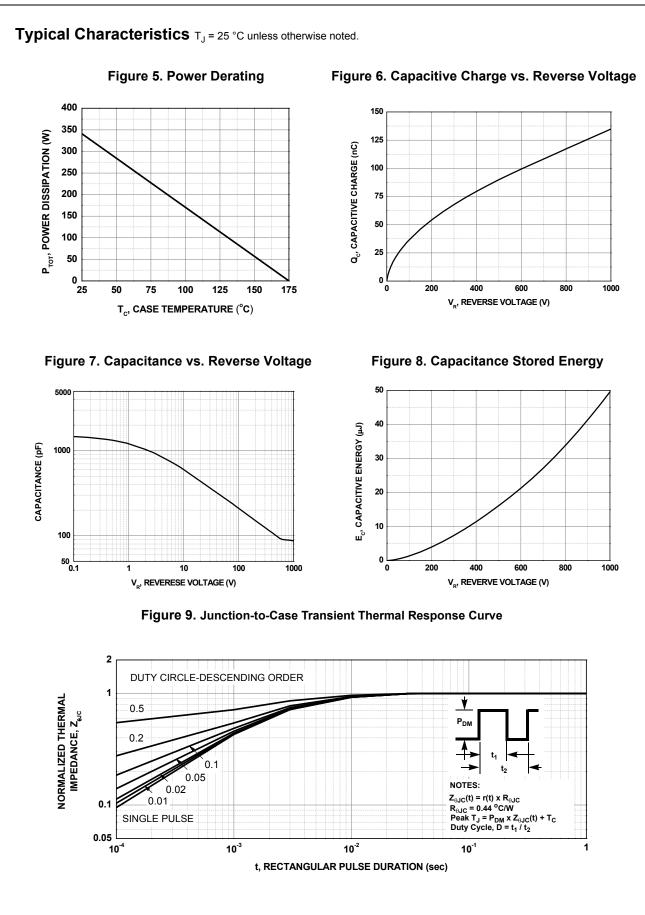
Figure 2. Reverse Characteristics





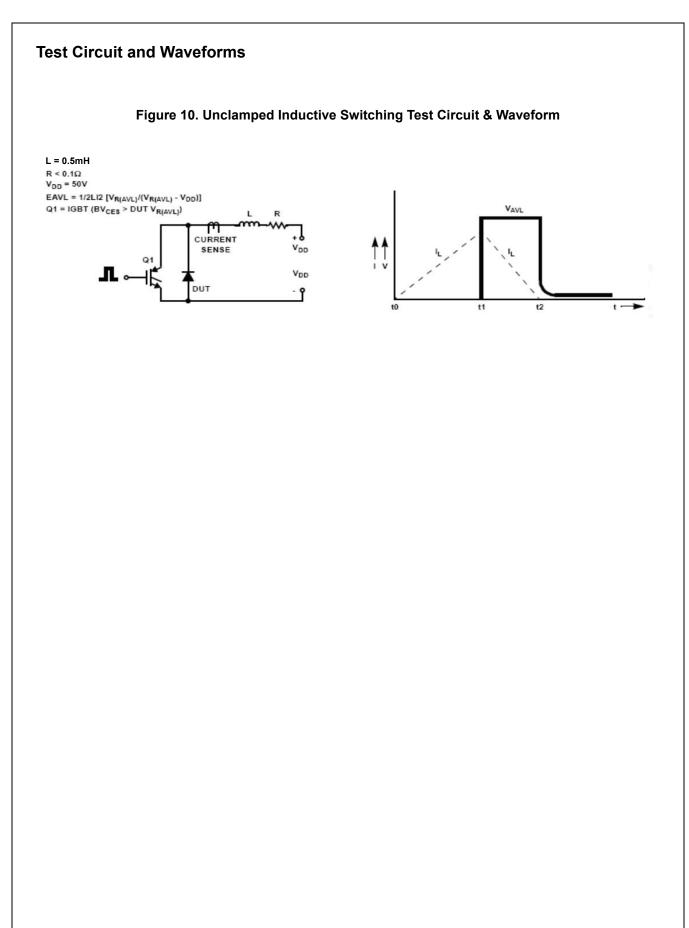


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FFSP20120A — Silicon Carbide Schottky Diode



Ø 4.09 3.50 ⊕ 0.36 M B A M 10.67 В Α 9.65 8.89 3.43 1.40 6.86 2.54 0.51 6.86 **7**° 5.84 3° T 13.40 16.51 12,19 14,22 16.15 9.40 15,75 8.38 **5**° **5°** 3° 3° 6.35 MAX 2 1 0.60 MAX С 14.73 13,60 1.65 (1.91)1.25 F Т 0.61 2.54 0.33 1.02 2.92 0.38 2.03 5.08 ⊕ 0.36 M C A B **5° 5°** 3° 3° -...... FAIRCHILD ... 4.80 4.30

NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DRAWING FILE NAME: TO220A02REV5

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